SEMI CONDUCTOR

40V N-Channel Enhancement Mode MOSFET

Voltage

Current 100A

Features

ΡΛΝ

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@20A<2.8m\Omega$
- R_{DS(ON)}, V_{GS}@4.5V, I_D@12A<3.5mΩ

40 V

- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

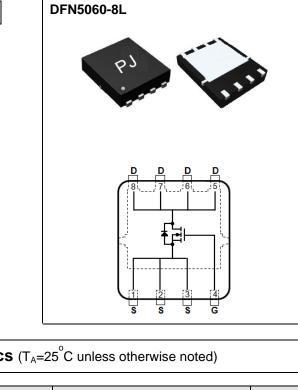
Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0028 ounces, 0.08 grams

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	40		
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V	
Continuous Drain Current (Note 4)	T _C =25°C		100		
	T _c =100°C	ID	64	А	
Pulsed Drain Current (Note 1)	T _C =25°C	I _{DM}	400		
Power Dissipation	T _C =25°C	5	70		
	T _c =100°C	Po	28	W	
Continuous Drain Current (Note 4)	T _A =25°C		17		
	T _A =70°C	ID	13	A	
Power Dissipation	T _A =25°C	5	2		
	T _A =70°C	Po	1.3	W	
Single Pulse Avalanche Energy (Note 6)		E _{AS}	312	mJ	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	R _{θJC}	1.8	°0.00	
	Junction to Ambient	R _{θJA}	62.5	°C/W	

• Limited only By Maximum Junction Temperature





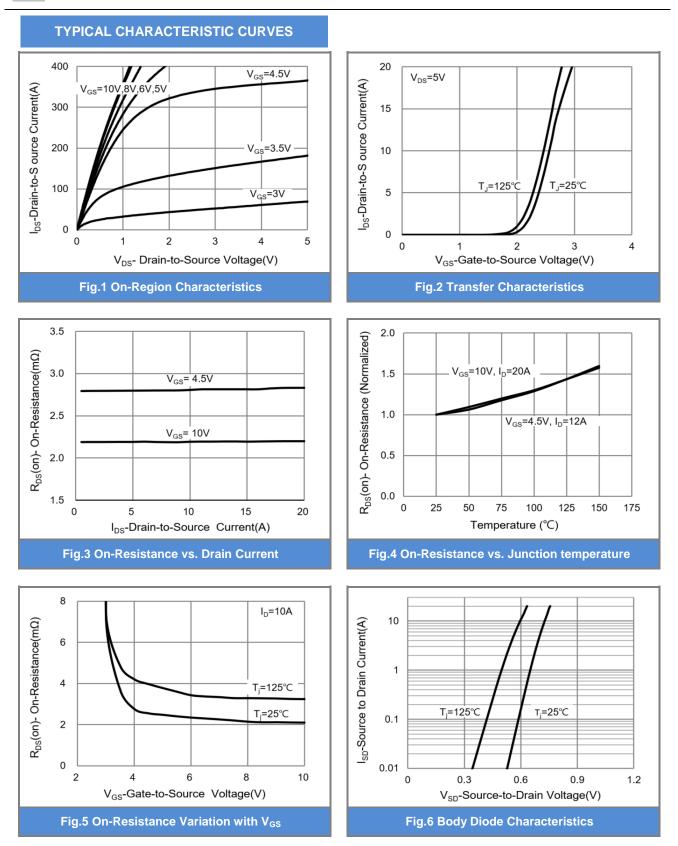
Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static			•		•	•
Drain-Source Breakdown Voltage	BV _{DSS}	BV _{DSS} V _{GS} =0V, I _D =250uA	40	-	-	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	1	1.54	2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A	-	2.2	2.8	mΩ
		V _{GS} =4.5V, I _D =12A	-	2.6	3.5	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =40V, V_{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	Qg	V _{DS} =20V, I _D =10A, V _{GS} =4.5V ^(Note 2,3)	-	50	-	nC
Gate-Source Charge	Q_{gs}		-	13	-	
Gate-Drain Charge	Q_gd		-	19	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1MHZ	-	5214	-	pF
Output Capacitance	Coss		-	492	-	
Reverse Transfer Capacitance	Crss		-	246	-	
Turn-On Delay Time	td _(on)	V_{DS} =20V, I_{D} =1A, V_{GS} =10V, R_{G} =6 Ω (Note 2,3)	-	44	-	ns
Turn-On Rise Time	t _r		-	43	-	
Turn-Off Delay Time	td _(off)		-	218	-	
Turn-Off Fall Time	t _f		-	62	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	100	А
Diode Forward Current	I _S					
Diode Forward Voltage	V_{SD}	I _S =1A, V _{GS} =0V	-	0.65	1	V

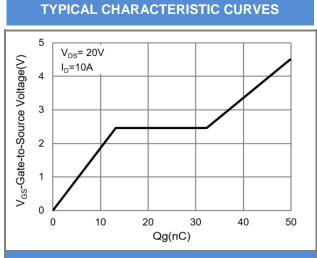
NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150$ °C. Ratings are based on low frequency and duty cycles to keep initial $T_J = 25$ °C.
- 4. The maximum current rating is package limited.
- 5. R_{®JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, I_{AS} =79A, V_{DD} =25V, V_{GS} =10V, Starting T_{J} =25°C.
- 7. Guaranteed by design, not subject to production testing.











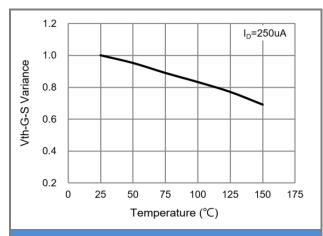
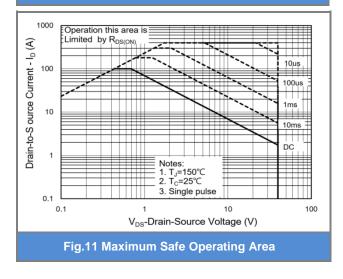
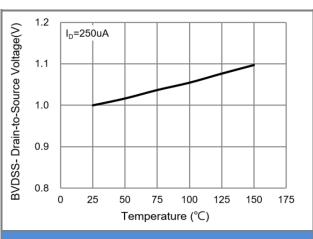


Fig.9 Threshold Voltage Variation with Temperature







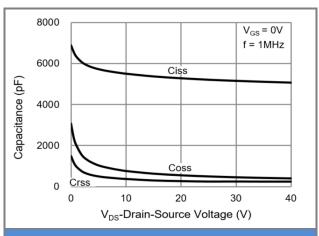
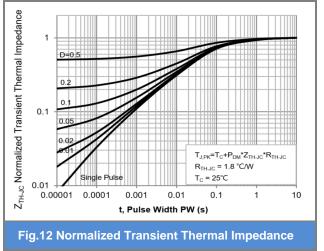


Fig.10 Capacitance vs. Drain-Source Voltage



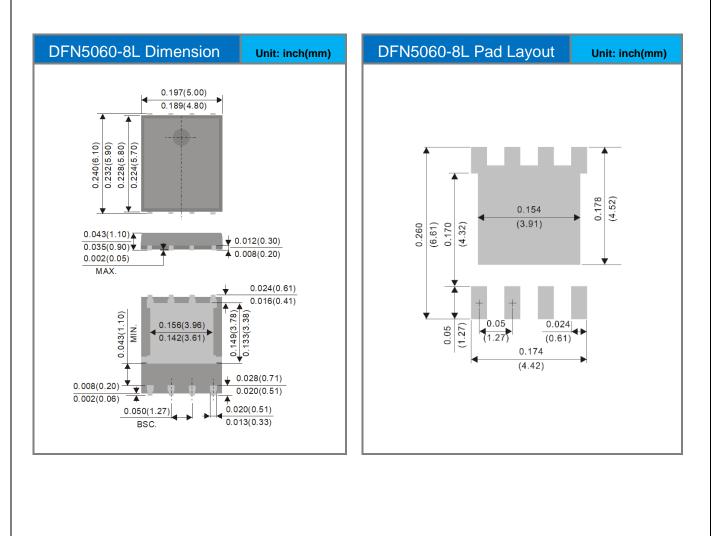




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ5440_R2_00001	DFN5060-8L	3000pcs / 13" reel	Q5440	Halogen free

Packaging Information & Mounting Pad Layout





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